

## Dual Digital Transistors (NPN+PNP)

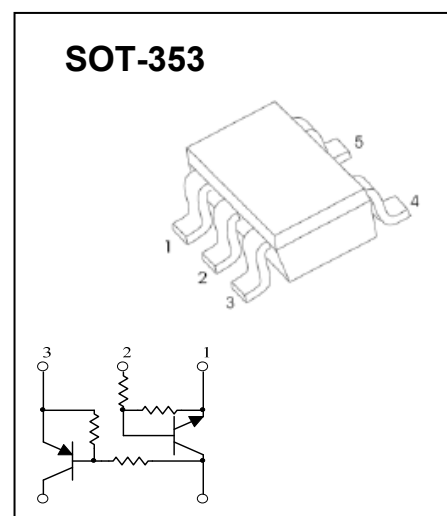
### FEATURES

- DTA114E and DTC114E transistors are built-in a package
- Ideal for power switch circuits
- Mounting cost and area can be cut in half

### MARKING: C3

#### NPN DTC114E Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V <sub>CC</sub>	50	V
Input voltage	V <sub>IN</sub>	-10~+40	V
Output current	I <sub>O</sub>	50	mA
	I <sub>CM</sub>	100	
Power dissipation	P <sub>D</sub>	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55~150	°C



#### Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input voltage	V <sub>I(off)</sub>	0.5			V	V <sub>CC</sub> =5V, I <sub>O</sub> =100μA
	V <sub>I(on)</sub>			3		V <sub>O</sub> =0.3V, I <sub>O</sub> =10mA
Output voltage	V <sub>O(on)</sub>			0.3	V	I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA
Input current	I <sub>I</sub>			0.88	mA	V <sub>I</sub> =5V
Output current	I <sub>O(off)</sub>			0.5	μA	V <sub>CC</sub> =50V, V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	30				V <sub>O</sub> =5V, I <sub>O</sub> =5mA
Input resistance	R <sub>1</sub>	7	10	13	kΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>CE</sub> =10V, I <sub>E</sub> =-5mA, f=100MHz

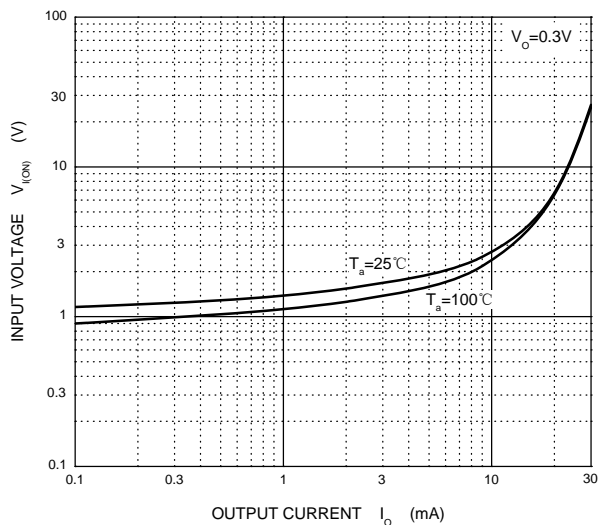
#### PNP DTA114E Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V <sub>CC</sub>	-50	V
Input voltage	V <sub>IN</sub>	-40~+10	V
Output current	I <sub>O</sub>	-50	mA
	I <sub>CM</sub>	-100	
Power dissipation	P <sub>D</sub>	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55~150	°C

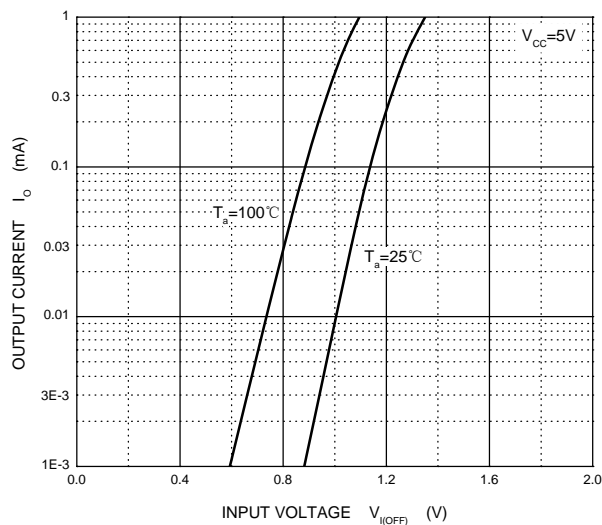
#### Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input voltage	V <sub>I(off)</sub>	-0.5			V	V <sub>CC</sub> =-5V, I <sub>O</sub> =-100μA
	V <sub>I(on)</sub>			-3		V <sub>O</sub> =-0.3V, I <sub>O</sub> =-10mA
Output voltage	V <sub>O(on)</sub>			-0.3	V	I <sub>O</sub> /I <sub>I</sub> =-10mA/-0.5mA
Input current	I <sub>I</sub>			-0.88	mA	V <sub>I</sub> =-5V
Output current	I <sub>O(off)</sub>			-0.5	μA	V <sub>CC</sub> =-50V, V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	30				V <sub>O</sub> =-5V, I <sub>O</sub> =-5mA
Input resistance	R <sub>1</sub>	7	10	13	kΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>CE</sub> =-10V, I <sub>E</sub> =5mA, f=100MHz

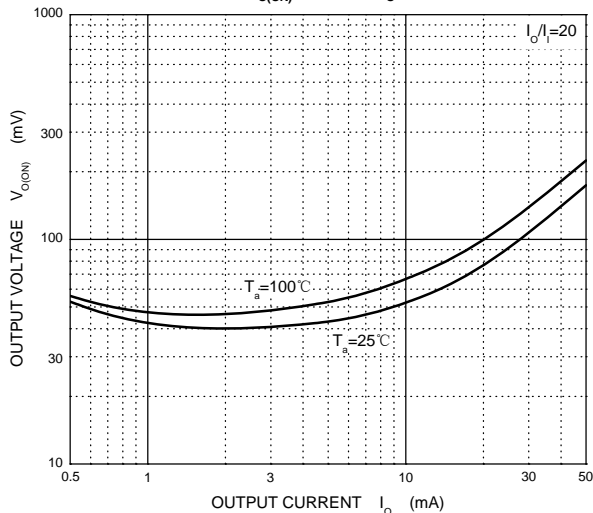
### ON Characteristics



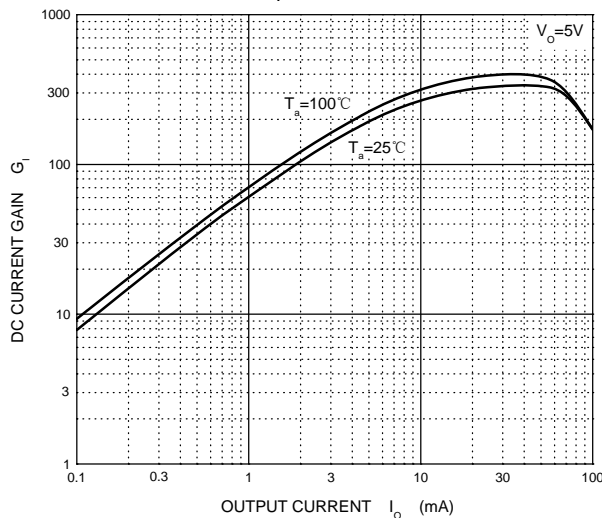
### OFF Characteristics



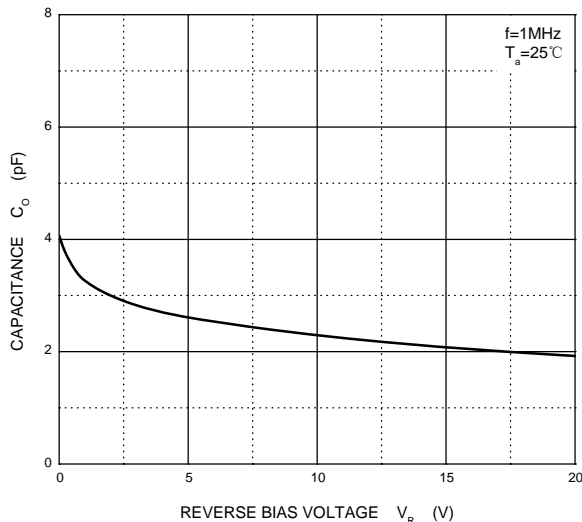
### $V_{O(ON)} - I_O$



### $G_I - I_O$



### $C_O - V_R$



### $P_D - T_a$

